

Welcome to [E-XFL.COM](#)

What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

| | |
|----------------------------|---|
| Product Status | Active |
| Core Processor | S08 |
| Core Size | 8-Bit |
| Speed | 20MHz |
| Connectivity | I ² C, LINbus, SPI, UART/USART |
| Peripherals | LVD, POR, PWM, WDT |
| Number of I/O | 26 |
| Program Memory Size | 16KB (16K x 8) |
| Program Memory Type | FLASH |
| EEPROM Size | 256 x 8 |
| RAM Size | 2K x 8 |
| Voltage - Supply (Vcc/Vdd) | 2.7V ~ 5.5V |
| Data Converters | A/D 12x12b |
| Oscillator Type | Internal |
| Operating Temperature | -40°C ~ 125°C (TA) |
| Mounting Type | Surface Mount |
| Package / Case | 32-LQFP |
| Supplier Device Package | 32-LQFP (7x7) |
| Purchase URL | https://www.e-xfl.com/pro/item?MUrl=&PartUrl=s9s08rn16w2mlc |

Table of Contents

| | | | |
|---|----|---|----|
| 1 Ordering parts..... | 4 | 5.2.2 Debug trace timing specifications..... | 16 |
| 1.1 Determining valid orderable parts..... | 4 | 5.2.3 FTM module timing..... | 17 |
| 2 Part identification..... | 4 | 5.3 Thermal specifications..... | 18 |
| 2.1 Description..... | 4 | 5.3.1 Thermal characteristics..... | 18 |
| 2.2 Format..... | 4 | 6 Peripheral operating requirements and behaviors..... | 19 |
| 2.3 Fields..... | 4 | 6.1 External oscillator (XOSC) and ICS characteristics..... | 19 |
| 2.4 Example..... | 5 | 6.2 NVM specifications..... | 21 |
| 3 Parameter Classification..... | 5 | 6.3 Analog..... | 23 |
| 4 Ratings..... | 5 | 6.3.1 ADC characteristics..... | 23 |
| 4.1 Thermal handling ratings..... | 5 | 6.3.2 Analog comparator (ACMP) electricals..... | 25 |
| 4.2 Moisture handling ratings..... | 6 | 6.4 Communication interfaces..... | 26 |
| 4.3 ESD handling ratings..... | 6 | 6.4.1 SPI switching specifications..... | 26 |
| 4.4 Voltage and current operating ratings..... | 6 | 6.5 Human-machine interfaces (HMI)..... | 29 |
| 5 General..... | 7 | 6.5.1 TSI electrical specifications..... | 29 |
| 5.1 Nonswitching electrical specifications..... | 7 | 7 Dimensions..... | 29 |
| 5.1.1 DC characteristics..... | 7 | 7.1 Obtaining package dimensions..... | 29 |
| 5.1.2 Supply current characteristics..... | 14 | 8 Pinout..... | 30 |
| 5.1.3 EMC performance..... | 15 | 8.1 Signal multiplexing and pin assignments..... | 30 |
| 5.2 Switching specifications..... | 15 | 8.2 Device pin assignment..... | 32 |
| 5.2.1 Control timing..... | 15 | 9 Revision history..... | 34 |

1 Ordering parts

1.1 Determining valid orderable parts

Valid orderable part numbers are provided on the web. To determine the orderable part numbers for this device, go to freescale.com and perform a part number search for the following device numbers: RN16 and RN8.

2 Part identification

2.1 Description

Part numbers for the chip have fields that identify the specific part. You can use the values of these fields to determine the specific part you have received.

2.2 Format

Part numbers for this device have the following format:

S 9 S08 RN AA F1 B CC

2.3 Fields

This table lists the possible values for each field in the part number (not all combinations are valid):

| Field | Description | Values |
|-------|------------------------------|--|
| S | Qualification status | <ul style="list-style-type: none">S = fully qualified, general market flow |
| 9 | Memory | <ul style="list-style-type: none">9 = flash based |
| S08 | Core | <ul style="list-style-type: none">S08 = 8-bit CPU |
| RN | Device family | <ul style="list-style-type: none">RN |
| AA | Approximate flash size in KB | <ul style="list-style-type: none">16 = 16 KB8 = 8 KB |
| F1 | Fab and mask set identifier | <ul style="list-style-type: none">W2 |
| B | Temperature range (°C) | <ul style="list-style-type: none">M = -40 to 125 |
| CC | Package designator | <ul style="list-style-type: none">LF = 48-LQFP |

2. Determined according to IPC/JEDEC Standard J-STD-020, *Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices*.

4.2 Moisture handling ratings

| Symbol | Description | Min. | Max. | Unit | Notes |
|--------|----------------------------|------|------|------|-------|
| MSL | Moisture sensitivity level | — | 3 | — | 1 |

1. Determined according to IPC/JEDEC Standard J-STD-020, *Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices*.

4.3 ESD handling ratings

| Symbol | Description | Min. | Max. | Unit | Notes |
|-----------|---|-------|-------|------|-------|
| V_{HBM} | Electrostatic discharge voltage, human body model | -6000 | +6000 | V | 1 |
| V_{CDM} | Electrostatic discharge voltage, charged-device model | -500 | +500 | V | 2 |
| I_{LAT} | Latch-up current at ambient temperature of 125°C | -100 | +100 | mA | 3 |

1. Determined according to JEDEC Standard JESD22-A114, *Electrostatic Discharge (ESD) Sensitivity Testing Human Body Model (HBM)*.
2. Determined according to JEDEC Standard JESD22-C101, *Field-Induced Charged-Device Model Test Method for Electrostatic-Discharge-Withstand Thresholds of Microelectronic Components*.
3. Determined according to JEDEC Standard JESD78D, IC Latch-up Test.
 - Test was performed at 125 °C case temperature (Class II).
 - I/O pins pass +100/-100 mA I-test with Idd current limit at 400mA.
 - I/O pins pass +20/-100 mA I-test with Idd current limit at 1000mA.
 - Supply groups pass 1.5 Vccmax.
 - RESET_B pin was only tested with negative I-test due to product conditioning requirement.

4.4 Voltage and current operating ratings

Absolute maximum ratings are stress ratings only, and functional operation at the maxima is not guaranteed. Stress beyond the limits specified in below table may affect device reliability or cause permanent damage to the device. For functional operating conditions, refer to the remaining tables in this document.

This device contains circuitry protecting against damage due to high static voltage or electrical fields; however, it is advised that normal precautions be taken to avoid application of any voltages higher than maximum-rated voltages to this high-impedance circuit. Reliability of operation is enhanced if unused inputs are tied to an appropriate logic voltage level (for instance, either V_{SS} or V_{DD}) or the programmable pullup resistor associated with the pin is enabled.

| Symbol | Description | Min. | Max. | Unit |
|-----------|---|----------------|----------------|------|
| V_{DD} | Supply voltage | -0.3 | 5.8 | V |
| I_{DD} | Maximum current into V_{DD} | — | 120 | mA |
| V_{DIO} | Digital input voltage (except RESET, EXTAL, XTAL, or true open drain pin PTA2 and PTA3) | -0.3 | $V_{DD} + 0.3$ | V |
| | Digital input voltage (true open drain pin PTA2 and PTA3) | -0.3 | 6 | V |
| V_{AIO} | Analog ¹ , RESET, EXTAL, and XTAL input voltage | -0.3 | $V_{DD} + 0.3$ | V |
| I_D | Instantaneous maximum current single pin limit (applies to all port pins) | -25 | 25 | mA |
| V_{DDA} | Analog supply voltage | $V_{DD} - 0.3$ | $V_{DD} + 0.3$ | V |

1. All digital I/O pins, except open-drain pin PTA2 and PTA3, are internally clamped to V_{SS} and V_{DD} . PTA2 and PTA3 is only clamped to V_{SS} .

5 General

5.1 Nonswitching electrical specifications

5.1.1 DC characteristics

This section includes information about power supply requirements and I/O pin characteristics.

Table 2. DC characteristics

| Symbol | C | Descriptions | | | Min | Typical ¹ | Max | Unit |
|-----------|---|---|---------------------------------------|---------------------------|----------------|----------------------|------|------|
| — | — | Operating voltage | | — | 2.7 | — | 5.5 | V |
| V_{OH} | C | Output high voltage | All I/O pins, standard-drive strength | 5 V, $I_{load} = -5$ mA | $V_{DD} - 0.8$ | — | — | V |
| | C | | | 3 V, $I_{load} = -2.5$ mA | $V_{DD} - 0.8$ | — | — | V |
| | C | High current drive pins, high-drive strength ² | | 5 V, $I_{load} = -20$ mA | $V_{DD} - 0.8$ | — | — | V |
| | C | | | 3 V, $I_{load} = -10$ mA | $V_{DD} - 0.8$ | — | — | V |
| I_{OHT} | D | Output high current | Max total I_{OH} for all ports | 5 V | — | — | -100 | mA |
| | | | | 3 V | — | — | -50 | |
| V_{OL} | C | Output low voltage | All I/O pins, standard-drive strength | 5 V, $I_{load} = 5$ mA | — | — | 0.8 | V |
| | C | | | 3 V, $I_{load} = 2.5$ mA | — | — | 0.8 | V |

Table continues on the next page...

Table 2. DC characteristics (continued)

| Symbol | C | Descriptions | | | Min | Typical ¹ | Max | Unit |
|---------------|---|---|--|---------------------------------------|----------------------|----------------------|----------------------|------------|
| | C | | High current drive pins, high-drive strength ² | 5 V, $I_{load} = 20$ mA | — | — | 0.8 | V |
| | C | | | 3 V, $I_{load} = 10$ mA | — | — | 0.8 | V |
| I_{OLT} | D | Output low current | Max total I_{OL} for all ports | 5 V | — | — | 100 | mA |
| | | | | 3 V | — | — | 50 | |
| V_{IH} | P | Input high voltage | All digital inputs | $V_{DD} > 4.5V$ | $0.70 \times V_{DD}$ | — | — | V |
| | C | | | $V_{DD} > 2.7V$ | $0.75 \times V_{DD}$ | — | — | |
| V_{IL} | P | Input low voltage | All digital inputs | $V_{DD} > 4.5V$ | — | — | $0.30 \times V_{DD}$ | V |
| | C | | | $V_{DD} > 2.7V$ | — | — | $0.35 \times V_{DD}$ | |
| V_{hys} | C | Input hysteresis | All digital inputs | — | $0.06 \times V_{DD}$ | — | — | mV |
| $ I_{in} $ | P | Input leakage current | All input only pins (per pin) | $V_{IN} = V_{DD}$ or V_{SS} | — | 0.1 | 1 | μA |
| $ I_{OZ} $ | P | Hi-Z (off-state) leakage current | All input/output (per pin) | $V_{IN} = V_{DD}$ or V_{SS} | — | 0.1 | 1 | μA |
| $ I_{OZTOT} $ | C | Total leakage combined for all inputs and Hi-Z pins | All input only and I/O | $V_{IN} = V_{DD}$ or V_{SS} | — | — | 2 | μA |
| R_{PU} | P | Pullup resistors | All digital inputs, when enabled (all I/O pins other than PTA2 and PTA3) | — | 30.0 | — | 50.0 | k Ω |
| R_{PU}^3 | P | Pullup resistors | PTA2 and PTA3 pin | — | 30.0 | — | 60.0 | k Ω |
| I_{IC} | D | DC injection current ^{4, 5, 6} | Single pin limit | $V_{IN} < V_{SS}$, $V_{IN} > V_{DD}$ | -0.2 | — | 2 | mA |
| | | | Total MCU limit, includes sum of all stressed pins | | -5 | — | 25 | |
| C_{in} | C | Input capacitance, all pins | | | — | — | 7 | pF |
| V_{RAM} | C | RAM retention voltage | | | 2.0 | — | — | V |

- Typical values are measured at 25 °C. Characterized, not tested.
- Only PTB4, PTB5 support ultra high current output.
- The specified resistor value is the actual value internal to the device. The pullup value may appear higher when measured externally on the pin.
- All functional non-supply pins, except for PTA2 and PTA3, are internally clamped to V_{SS} and V_{DD} .
- Input must be current-limited to the value specified. To determine the value of the required current-limiting resistor, calculate resistance values for positive and negative clamp voltages, then use the large one.
- Power supply must maintain regulation within operating V_{DD} range during instantaneous and operating maximum current conditions. If the positive injection current ($V_{IN} > V_{DD}$) is higher than I_{DD} , the injection current may flow out of V_{DD} and could result in external power supply going out of regulation. Ensure that external V_{DD} load will shunt current higher than maximum injection current when the MCU is not consuming power, such as no system clock is present, or clock rate is very low (which would reduce overall power consumption).

Table 3. LVD and POR Specification

| Symbol | C | Description | | Min | Typ | Max | Unit |
|---------------------|---|---|-----------------------------|------|------|------|------|
| V _{POR} | D | POR re-arm voltage ^{1, 2} | | 1.5 | 1.75 | 2.0 | V |
| V _{LVDH} | C | Falling low-voltage detect threshold - high range (LVDV = 1) ³ | | 4.2 | 4.3 | 4.4 | V |
| V _{LVW1H} | C | Falling low-voltage warning threshold - high range | Level 1 falling (LVWV = 00) | 4.3 | 4.4 | 4.5 | V |
| V _{LVW2H} | C | | Level 2 falling (LVWV = 01) | 4.5 | 4.5 | 4.6 | V |
| V _{LVW3H} | C | | Level 3 falling (LVWV = 10) | 4.6 | 4.6 | 4.7 | V |
| V _{LVW4H} | C | | Level 4 falling (LVWV = 11) | 4.7 | 4.7 | 4.8 | V |
| V _{HYSH} | C | High range low-voltage detect/warning hysteresis | | — | 100 | — | mV |
| V _{LVDL} | C | Falling low-voltage detect threshold - low range (LVDV = 0) | | 2.56 | 2.61 | 2.66 | V |
| V _{LVDW1L} | C | Falling low-voltage warning threshold - low range | Level 1 falling (LVWV = 00) | 2.62 | 2.7 | 2.78 | V |
| V _{LVDW2L} | C | | Level 2 falling (LVWV = 01) | 2.72 | 2.8 | 2.88 | V |
| V _{LVDW3L} | C | | Level 3 falling (LVWV = 10) | 2.82 | 2.9 | 2.98 | V |
| V _{LVDW4L} | C | | Level 4 falling (LVWV = 11) | 2.92 | 3.0 | 3.08 | V |
| V _{HYSDL} | C | Low range low-voltage detect hysteresis | | — | 40 | — | mV |
| V _{HYSWL} | C | Low range low-voltage warning hysteresis | | — | 80 | — | mV |
| V _{BG} | P | Buffered bandgap output ⁴ | | 1.14 | 1.16 | 1.18 | V |

1. Maximum is highest voltage that POR is guaranteed.
2. POR ramp time must be longer than 20us/V to get a stable startup.
3. Rising thresholds are falling threshold + hysteresis.
4. Voltage factory trimmed at V_{DD} = 5.0 V, Temp = 125 °C

Typical I_{OL} Vs. V_{OL} (low drive strength) ($V_{DD} = 5\text{ V}$)

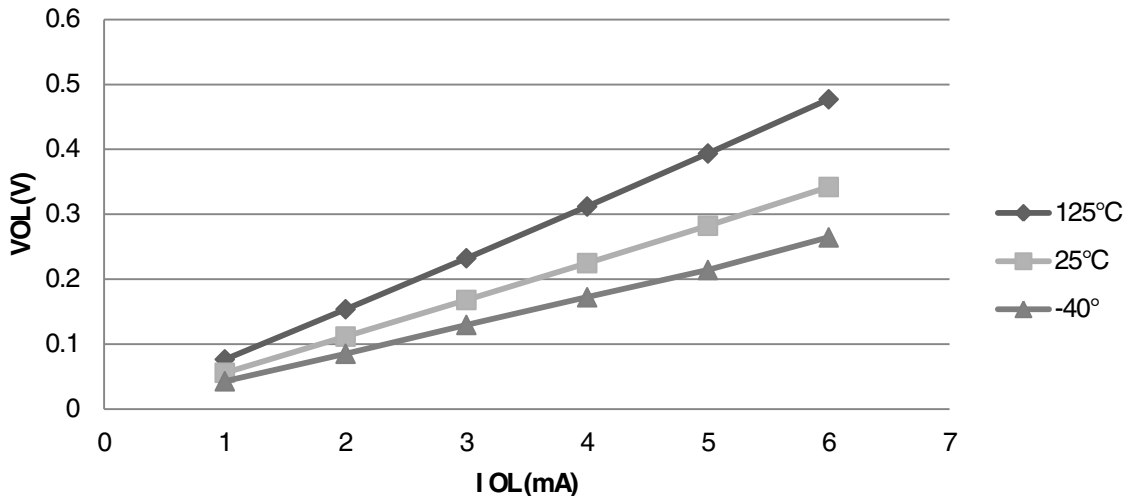


Figure 5. Typical I_{OL} Vs. V_{OL} (standard drive strength) ($V_{DD} = 5\text{ V}$)

Typical I_{OL} Vs. V_{OL} (low drive strength) ($V_{DD} = 3\text{ V}$)

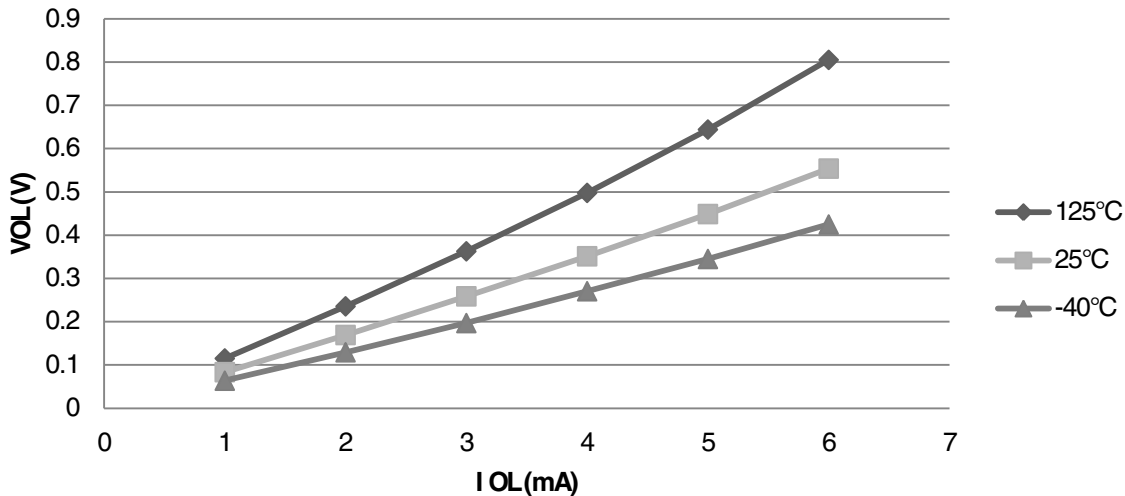


Figure 6. Typical I_{OL} Vs. V_{OL} (standard drive strength) ($V_{DD} = 3\text{ V}$)

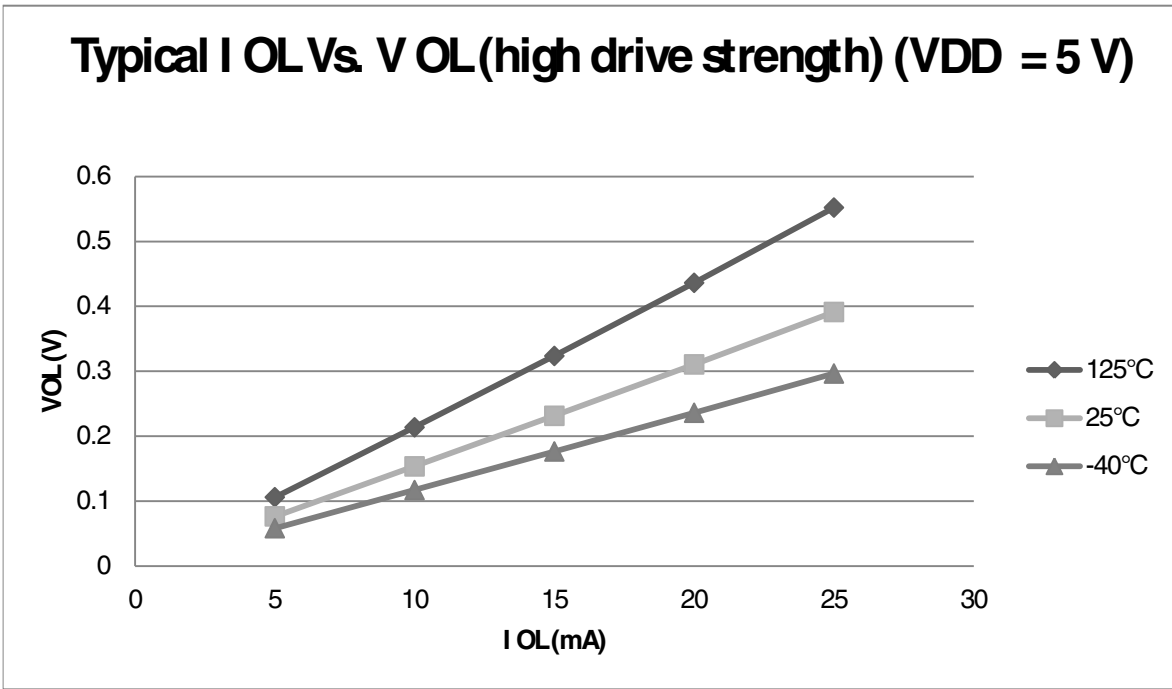


Figure 7. Typical I_{OL} Vs. V_{OL} (high drive strength) ($V_{DD} = 5\text{ V}$)

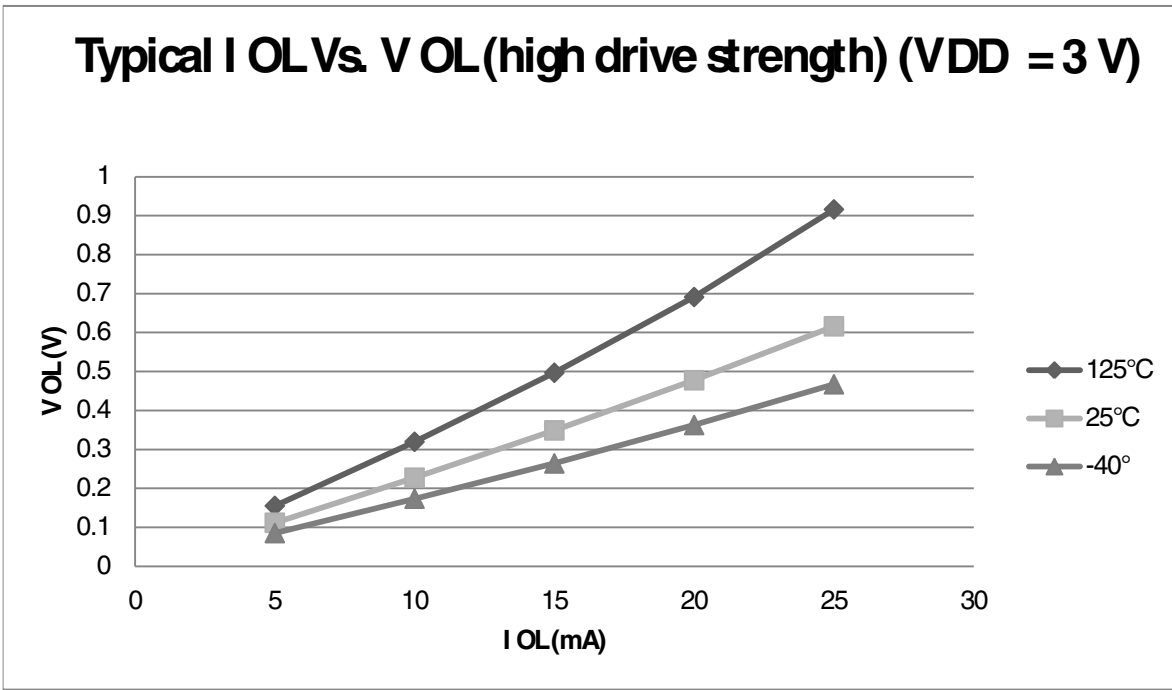


Figure 8. Typical I_{OL} Vs. V_{OL} (high drive strength) ($V_{DD} = 3\text{ V}$)

Table 4. Supply current characteristics (continued)

| Num | C | Parameter | Symbol | Bus Freq | V _{DD} (V) | Typical ¹ | Max | Unit | Temp |
|-----|---|---|--------|----------|---------------------|----------------------|-----|------|---------------|
| | C | ADLPC = 1 ADLSMP = 1 ADCO = 1 MODE = 10B ADICLK = 11B | | | 3 | 39 | — | | |
| 8 | C | TSI adder to stop3 ⁴ | — | — | 5 | 121 | — | μA | -40 to 125 °C |
| | C | PS = 010B NSCN = 0x0F EXTCHRG = 0 REFCHRG = 0 DVOLT = 01B | | | 3 | 120 | — | | |
| 9 | C | LVD adder to stop3 ⁵ | — | — | 5 | 128 | — | μA | -40 to 125 °C |
| | C | | | | 3 | 124 | — | | |

1. Data in Typical column was characterized at 5.0 V, 25 °C or is typical recommended value.
2. RTC adder cause <1 μA I_{DD} increase typically, RTC clock source is 1kHz LPO clock.
3. ACMP adder cause <10 μA I_{DD} increase typically.
4. The current varies with TSI configuration and capacity of touch electrode. Please refer to [TSI electrical specifications](#).
5. LVD is periodically woken up from stop3 by 5% duty cycle. The period is equal to or less than 2 ms.

5.1.3 EMC performance

Electromagnetic compatibility (EMC) performance is highly dependent on the environment in which the MCU resides. Board design and layout, circuit topology choices, location and characteristics of external components as well as MCU software operation all play a significant role in EMC performance. The system designer should consult Freescale applications notes such as [AN2321](#), [AN1050](#), [AN1263](#), [AN2764](#), and [AN1259](#) for advice and guidance specifically targeted at optimizing EMC performance.

5.2 Switching specifications

5.2.1 Control timing

Table 5. Control timing

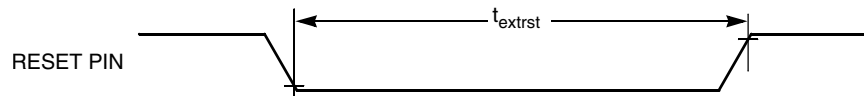
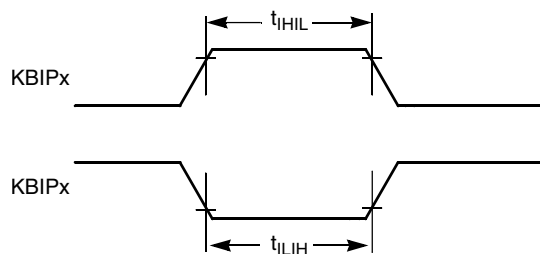
| Num | C | Rating | Symbol | Min | Typical ¹ | Max | Unit |
|-----|---|---|-----------|------|----------------------|------|------|
| 1 | P | Bus frequency ($t_{cyc} = 1/f_{Bus}$) | f_{Bus} | DC | — | 20 | MHz |
| 2 | P | Internal low power oscillator frequency | f_{LPO} | 0.67 | 1.0 | 1.25 | KHz |

Table continues on the next page...

Table 5. Control timing (continued)

| Num | C | Rating | Symbol | Min | Typical ¹ | Max | Unit |
|-----|---|--|--------------------------------|------------------------------|----------------------|------|------|
| 3 | D | External reset pulse width ² | t_{extrst} | $1.5 \times t_{Self_reset}$ | — | — | ns |
| 4 | D | Reset low drive | t_{rstdrv} | $34 \times t_{cyc}$ | — | — | ns |
| 5 | D | BKGD/MS setup time after issuing background debug force reset to enter user or BDM modes | t_{MSSU} | 500 | — | — | ns |
| 6 | D | BKGD/MS hold time after issuing background debug force reset to enter user or BDM modes ³ | t_{MSH} | 100 | — | — | ns |
| 7 | D | Keyboard interrupt pulse width | Asynchronous path ² | t_{LIH} | 100 | — | ns |
| | D | | Synchronous path | t_{IHIL} | $1.5 \times t_{cyc}$ | — | ns |
| 8 | C | Port rise and fall time - standard drive strength (load = 50 pF) ⁴ | — | t_{Rise} | — | 10.2 | ns |
| | C | | — | t_{Fall} | — | 9.5 | ns |
| | C | Port rise and fall time - high drive strength (load = 50 pF) ⁴ | — | t_{Rise} | — | 5.4 | ns |
| | C | | — | t_{Fall} | — | 4.6 | ns |

- Typical values are based on characterization data at $V_{DD} = 5.0\text{ V}$, $25\text{ }^{\circ}\text{C}$ unless otherwise stated.
- This is the shortest pulse that is guaranteed to be recognized as a reset pin request.
- To enter BDM mode following a POR, BKGD/MS must be held low during the powerup and for a hold time of t_{MSH} after V_{DD} rises above V_{LVD} .
- Timing is shown with respect to 20% V_{DD} and 80% V_{DD} levels. Temperature range $-40\text{ }^{\circ}\text{C}$ to $125\text{ }^{\circ}\text{C}$.


Figure 9. Reset timing

Figure 10. KBIPx timing

5.2.2 Debug trace timing specifications

Table 6. Debug trace operating behaviors

| Symbol | Description | Min. | Max. | Unit |
|-----------|-----------------|---------------------|------|------|
| t_{cyc} | Clock period | Frequency dependent | | MHz |
| t_{wl} | Low pulse width | 2 | — | ns |

Table continues on the next page...

Table 8. Thermal characteristics (continued)

| Rating | Symbol | Value | Unit |
|--------------|---------------|-------|------|
| 48-pin LQFP | θ_{JA} | 58 | °C/W |
| 32-pin LQFP | θ_{JA} | 59 | °C/W |
| 20-pin TSSOP | θ_{JA} | 76 | °C/W |
| 16-pin TSSOP | θ_{JA} | 87 | °C/W |

The average chip-junction temperature (T_J) in °C can be obtained from:

$$T_J = T_A + (P_D \times \theta_{JA})$$

Where:

T_A = Ambient temperature, °C

θ_{JA} = Package thermal resistance, junction-to-ambient, °C/W

$$P_D = P_{int} + P_{I/O}$$

$P_{int} = I_{DD} \times V_{DD}$, Watts - chip internal power

$P_{I/O}$ = Power dissipation on input and output pins - user determined

For most applications, $P_{I/O} \ll P_{int}$ and can be neglected. An approximate relationship between P_D and T_J (if $P_{I/O}$ is neglected) is:

$$P_D = K \div (T_J + 273 \text{ °C})$$

Solving the equations above for K gives:

$$K = P_D \times (T_A + 273 \text{ °C}) + \theta_{JA} \times (P_D)^2$$

where K is a constant pertaining to the particular part. K can be determined by measuring P_D (at equilibrium) for a known T_A . Using this value of K, the values of P_D and T_J can be obtained by solving the above equations iteratively for any value of T_A .

6 Peripheral operating requirements and behaviors

6.1 External oscillator (XOSC) and ICS characteristics

Table 9. XOSC and ICS specifications (temperature range = -40 to 125 °C ambient)

| Num | C | Characteristic | | Symbol | Min | Typical ¹ | Max | Unit |
|-----|---|--|--|---------------------|-----------------------|----------------------|------|-------------|
| 1 | C | Oscillator crystal or resonator | Low range (RANGE = 0) | f_{lo} | 32 | — | 40 | kHz |
| | C | | High range (RANGE = 1) FEE or FBE mode ² | f_{hi} | 4 | — | 20 | MHz |
| | C | | High range (RANGE = 1), high gain (HGO = 1), FBELP mode | f_{hi} | 4 | — | 20 | MHz |
| | C | | High range (RANGE = 1), low power (HGO = 0), FBELP mode | f_{hi} | 4 | — | 20 | MHz |
| 2 | D | Load capacitors | | C1, C2 | See Note ³ | | | |
| 3 | D | Feedback resistor | Low Frequency, Low-Power Mode ⁴ | R_F | — | — | — | MΩ |
| | | | Low Frequency, High-Gain Mode | | — | 10 | — | MΩ |
| | | | High Frequency, Low-Power Mode | | — | 1 | — | MΩ |
| | | | High Frequency, High-Gain Mode | | — | 1 | — | MΩ |
| 4 | D | Series resistor - Low Frequency | Low-Power Mode ⁴ | R_S | — | — | — | kΩ |
| | | | High-Gain Mode | | — | 200 | — | kΩ |
| 5 | D | Series resistor - High Frequency | Low-Power Mode ⁴ | R_S | — | — | — | kΩ |
| | D | Series resistor - High Frequency, High-Gain Mode | 4 MHz | | — | 0 | — | kΩ |
| | D | | 8 MHz | | — | 0 | — | kΩ |
| | D | | 16 MHz | | — | 0 | — | kΩ |
| 6 | C | Crystal start-up time Low range = 39.0625 kHz crystal; High range = 20 MHz crystal ^{5, 6} | Low range, low power | t_{CSTL} | — | 1000 | — | ms |
| | C | | Low range, high power | | — | 800 | — | ms |
| | C | | High range, low power | t_{CSTH} | — | 3 | — | ms |
| | C | | High range, high power | | — | 1.5 | — | ms |
| 7 | T | Internal reference start-up time | | t_{IRST} | — | 20 | 50 | μs |
| 8 | D | Square wave input clock frequency | FEE or FBE mode ² | f_{extal} | 0.03125 | — | 5 | MHz |
| | D | | FBELP mode | | 0 | — | 20 | MHz |
| 9 | P | Average internal reference frequency - trimmed | | f_{int_t} | — | 39.0625 | — | kHz |
| 10 | P | DCO output frequency range - trimmed | | f_{dco_t} | 16 | — | 20 | MHz |
| 11 | P | Total deviation of DCO output from trimmed frequency ⁵ | Over full voltage range and temperature range of -40 to 125 °C | Δf_{dco_t} | — | — | ±2.0 | |
| | C | | Over full voltage range and temperature range of -40 to 105 °C | | | | ±1.5 | % f_{dco} |

Table continues on the next page...

**Table 9. XOSC and ICS specifications (temperature range = -40 to 125 °C ambient)
(continued)**

| Num | C | Characteristic | Symbol | Min | Typical ¹ | Max | Unit |
|-----|---|---|---------------|-----|----------------------|------|-------------|
| | C | Over fixed voltage and temperature range of 0 to 70 °C | | | | ±1.0 | |
| 12 | C | FLL acquisition time ^{5, 7} | $t_{Acquire}$ | — | — | 2 | ms |
| 13 | C | Long term jitter of DCO output clock (averaged over 2 ms interval) ⁸ | C_{Jitter} | — | 0.02 | 0.2 | % f_{dco} |

1. Data in Typical column was characterized at 5.0 V, 25 °C or is typical recommended value.
2. When ICS is configured for FEE or FBE mode, input clock source must be divisible using RDIV to within the range of 31.25 kHz to 39.0625 kHz.
3. See crystal or resonator manufacturer's recommendation.
4. Load capacitors (C_1, C_2), feedback resistor (R_F) and series resistor (R_S) are incorporated internally when RANGE = HGO = 0.
5. This parameter is characterized and not tested on each device.
6. Proper PC board layout procedures must be followed to achieve specifications.
7. This specification applies to any time the FLL reference source or reference divider is changed, trim value changed, or changing from FLL disabled (FBELP, FBILP) to FLL enabled (FEI, FEE, FBE, FBI). If a crystal/resonator is being used as the reference, this specification assumes it is already running.
8. Jitter is the average deviation from the programmed frequency measured over the specified interval at maximum f_{Bus} . Measurements are made with the device powered by filtered supplies and clocked by a stable external clock signal. Noise injected into the FLL circuitry via V_{DD} and V_{SS} and variation in crystal oscillator frequency increase the C_{Jitter} percentage for a given interval.

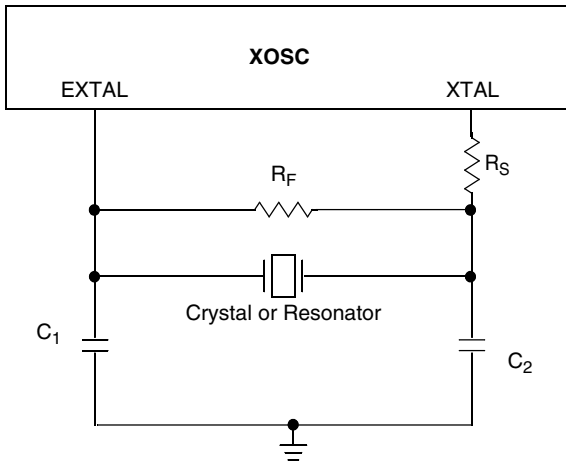


Figure 15. Typical crystal or resonator circuit

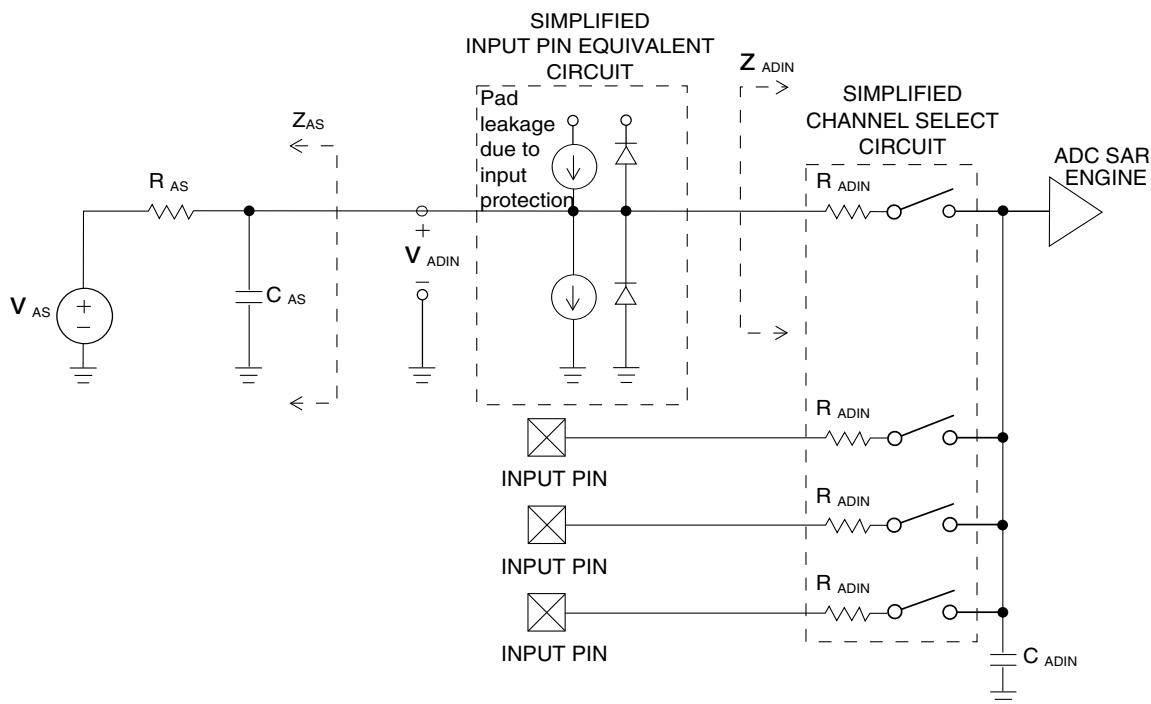


Figure 16. ADC input impedance equivalency diagram

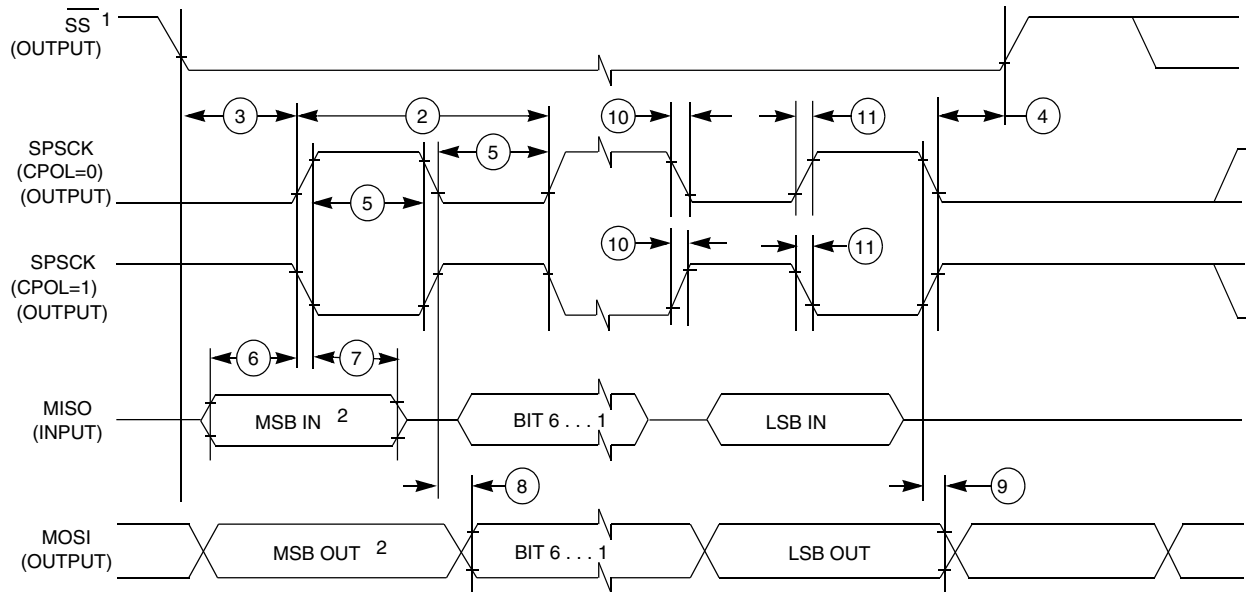
Table 12. 12-bit ADC Characteristics ($V_{REFH} = V_{DDA}$, $V_{REFL} = V_{SSA}$)

| Characteristic | Conditions | C | Symb | Min | Typ ¹ | Max | Unit |
|---|-------------------------|---|-------------|-----|------------------|-----|---------|
| Supply current ADLPC = 1 ADLSMP = 1 ADCO = 1 | | T | I_{DDA} | — | 133 | — | μA |
| Supply current ADLPC = 1 ADLSMP = 0 ADCO = 1 | | T | I_{DDA} | — | 218 | — | μA |
| Supply current ADLPC = 0 ADLSMP = 1 ADCO = 1 | | T | I_{DDA} | — | 327 | — | μA |
| Supply current ADLPC = 0 ADLSMP = 0 ADCO = 1 | | T | I_{DDAD} | — | 582 | 990 | μA |
| Supply current | Stop, reset, module off | T | I_{DDA} | — | 0.011 | 1 | μA |
| ADC asynchronous clock source | High speed (ADLPC = 0) | P | f_{ADACK} | 2 | 3.3 | 5 | MHz |

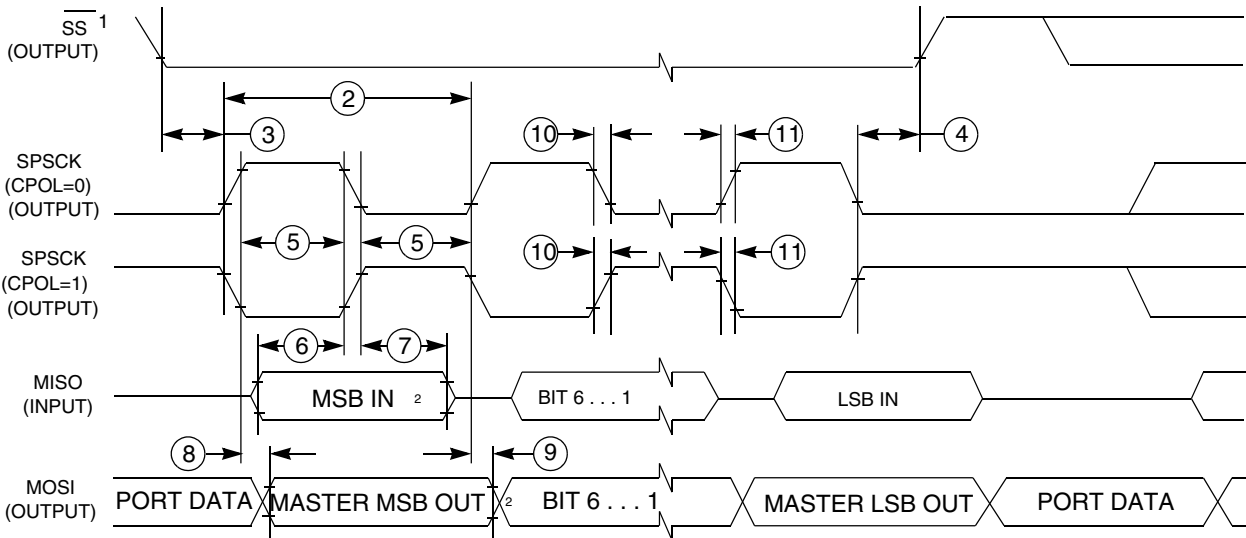
Table continues on the next page...

Table 14. SPI master mode timing (continued)

| Nu m. | Symbol | Description | Min. | Max. | Unit | Comment |
|----------|----------|------------------|------|------|------|---------|
| | t_{FI} | Fall time input | | | | |
| 11 | t_{RO} | Rise time output | — | 25 | ns | — |
| | t_{FO} | Fall time output | | | | |



1. If configured as an output.
2. LSBF = 0. For LSBF = 1, bit order is LSB, bit 1, ..., bit 6, MSB.

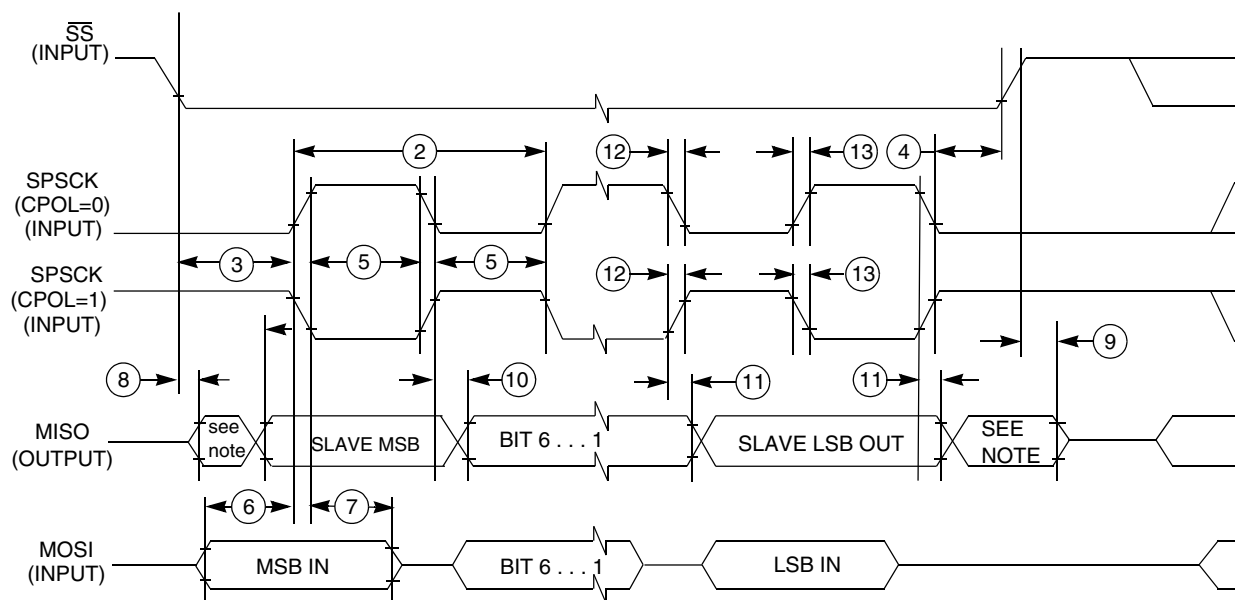
Figure 17. SPI master mode timing (CPHA=0)


1. If configured as output
2. LSBF = 0. For LSBF = 1, bit order is LSB, bit 1, ..., bit 6, MSB.

Figure 18. SPI master mode timing (CPHA=1)

Table 15. SPI slave mode timing

| Nu m. | Symbol | Description | Min. | Max. | Unit | Comment |
|-------|--------------|--------------------------------|--------------------|----------------|-----------|---|
| 1 | f_{op} | Frequency of operation | 0 | $f_{Bus}/4$ | Hz | f_{Bus} is the bus clock as defined in . |
| 2 | t_{SPSCK} | SPSCK period | $4 \times t_{Bus}$ | — | ns | $t_{Bus} = 1/f_{Bus}$ |
| 3 | t_{Lead} | Enable lead time | 1 | — | t_{Bus} | — |
| 4 | t_{Lag} | Enable lag time | 1 | — | t_{Bus} | — |
| 5 | t_{WSPSCK} | Clock (SPSCK) high or low time | $t_{Bus} - 30$ | — | ns | — |
| 6 | t_{SU} | Data setup time (inputs) | 15 | — | ns | — |
| 7 | t_{HI} | Data hold time (inputs) | 25 | — | ns | — |
| 8 | t_a | Slave access time | — | t_{Bus} | ns | Time to data active from high-impedance state |
| 9 | t_{dis} | Slave MISO disable time | — | t_{Bus} | ns | Hold time to high-impedance state |
| 10 | t_v | Data valid (after SPSCK edge) | — | 25 | ns | — |
| 11 | t_{HO} | Data hold time (outputs) | 0 | — | ns | — |
| 12 | t_{RI} | Rise time input | — | $t_{Bus} - 25$ | ns | — |
| | t_{FI} | Fall time input | — | $t_{Bus} - 25$ | ns | — |
| 13 | t_{RO} | Rise time output | — | 25 | ns | — |
| | t_{FO} | Fall time output | — | 25 | ns | — |



NOTE: Not defined

Figure 19. SPI slave mode timing (CPHA = 0)

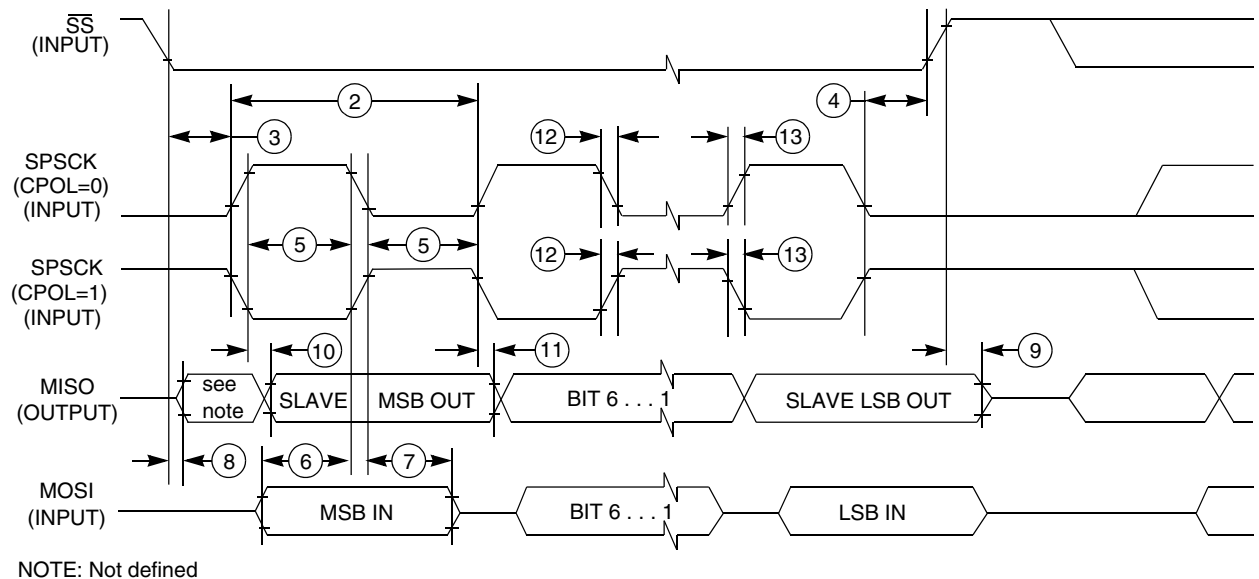


Figure 20. SPI slave mode timing (CPHA=1)

6.5 Human-machine interfaces (HMI)

6.5.1 TSI electrical specifications

Table 16. TSI electrical specifications

| Symbol | Description | Min. | Type | Max | Unit |
|-----------|--|------|------|-----|------|
| TSI_RUNF | Fixed power consumption in run mode | — | 100 | — | μA |
| TSI_RUNV | Variable power consumption in run mode (depends on oscillator's current selection) | 1.0 | — | 128 | μA |
| TSI_EN | Power consumption in enable mode | — | 100 | — | μA |
| TSI_DIS | Power consumption in disable mode | — | 1.2 | — | μA |
| TSI_TEN | TSI analog enable time | — | 66 | — | μs |
| TSI_CREF | TSI reference capacitor | — | 1.0 | — | pF |
| TSI_DVOLT | Voltage variation of VP & VM around nominal values | -10 | — | 10 | % |

7 Dimensions

7.1 Obtaining package dimensions

Package dimensions are provided in package drawings.

highest priority module will have control over the pin. Selecting a higher priority pin function with a lower priority function already enabled can cause spurious edges to the lower priority module. Disable all modules that share a pin before enabling another module.

8.2 Device pin assignment

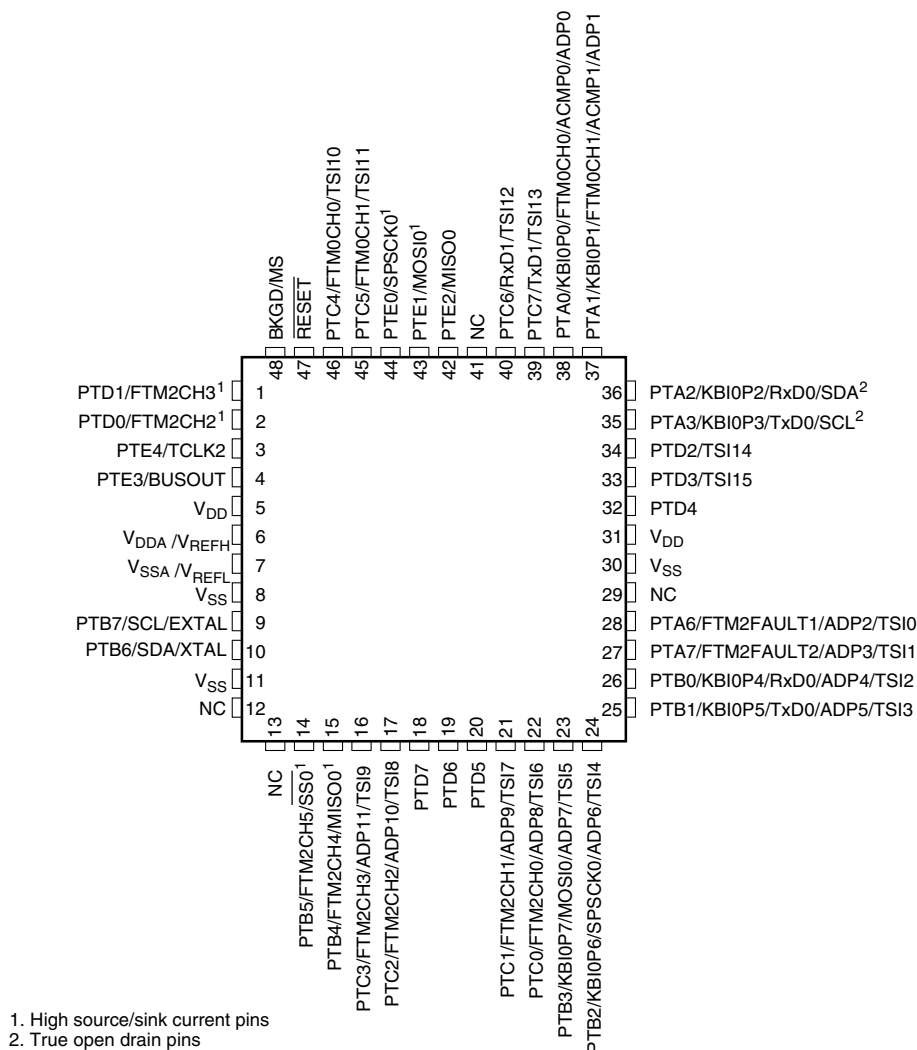
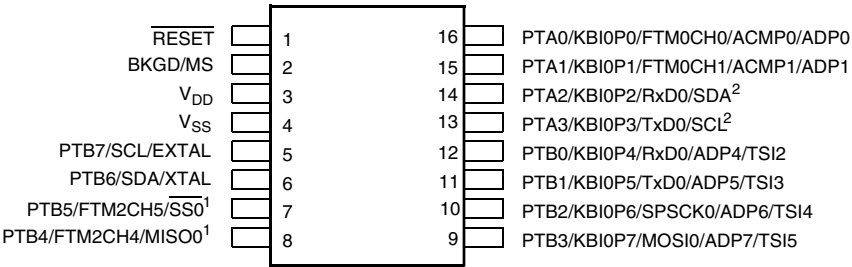


Figure 21. S9S08RN16 48-pin LQFP package



1. High source/sink current pins
2. True open drain pins

Figure 24. S9S08RN16 16-pin TSSOP package

9 Revision history

The following table provides a revision history for this document.

Table 18. Revision history

| Rev. No. | Date | Substantial Changes |
|----------|---------|---------------------|
| 1 | 02/2014 | Initial Release |

How to Reach Us:**Home Page:**freescale.com**Web Support:**freescale.com/support

Information in this document is provided solely to enable system and software implementers to use Freescale products. There are no express or implied copyright licenses granted hereunder to design or fabricate any integrated circuits based on the information in this document.

Freescale reserves the right to make changes without further notice to any products herein.

Freescale makes no warranty, representation, or guarantee regarding the suitability of its products for any particular purpose, nor does Freescale assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages.

“Typical” parameters that may be provided in Freescale data sheets and/or specifications can and do vary in different applications, and actual performance may vary over time. All operating parameters, including “typicals,” must be validated for each customer application by customer's technical experts. Freescale does not convey any license under its patent rights nor the rights of others. Freescale sells products pursuant to standard terms and conditions of sale, which can be found at the following address: freescale.com/SalesTermsandConditions.

Freescale, the Freescale logo, CodeWarrior and Processor Expert are trademarks of Freescale Semiconductor, Inc., Reg. U.S. Pat. & Tm. Off. Tower is a trademark of Freescale Semiconductor, Inc. All other product or service names are the property of their respective owners.

© 2014 Freescale Semiconductor, Inc.